



MS AF
REPLY UNDER
37 C.F.R. § 1.116
EXPEDITED PROCEDURE
EXAMINING GROUP 2826

PATENT
002-4652P
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IN THE U.S. PATENT AND TRADEMARK OFFICE

Applicant: Narihiro MOROSAWA et al. Conf.: 7107
Appl. No.: 09/471,173 Group: 2826
Filed: December 23, 1999 Examiner: QUINTO, Kevin
For: INSULATED GATE TRANSISTOR AND PROCESS
FOR FABRICATING THE SAME

REPLY AFTER FINAL UNDER 37 C.F.R. § 1.116

MS AF

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

August 8, 2003

Sir:

In reply to the Office Action dated May 21, 2003, the following amendments and remarks are respectfully submitted in connection with the above-identified application.

This reply includes List of claims and Remarks.